



650V SiC Schottky Diode

VDC	650 V
Q _c	26 nC
I _F	10 A
T _j ,max	175 °C

Amp+[™] Features

- Unipolar rectifier with surge current
- Zero reverse recovery current
- · Fast, temperature-independent switching
- Avalanche tested to 67mJ*

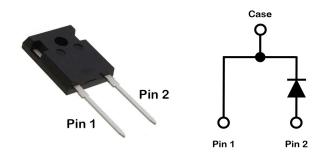
Amp+ TM Benefits

- Zero switching loss
- Higher efficiency
- Smaller heat sink
- Easy to parallel

Amp+[™] Applications

- General Purpose
- Switched mode power supplies, UPS
- Power factor correction
- · Output rectification

Package



Part #	Package	Marking
GP3D010A065B	TO-247-2L	3D010A065



Maximum Ratings, at T_i=25 °C, unless otherwise specified

Characteristics	Symbol	Conditions	Values	Unit
		T _C =25 °C, T _j =175 °C	28	
Continuous forward current	l _F **	T _C =125 °C, T _j =175 °C	15	A
		T _C =150 °C, T _j =175 °C	9	
Surge non-repetitive forward current	1	T _C =25 °C, t _p =8.3 ms	80	Α Α
sine halfwave	I _{FSM}	T _C =110 °C, t _p =8.3 ms	70	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t _p =10 μs	575	A
i^2t value	∫i²dt	T _C =25 °C, t _p =8.3 ms	27	A ² s
i t value		T _C =110 °C, t _p =8.3 ms	20	As
Repetitive peak reverse voltage	V_{RRM}	T _j =25 °C	650	V
Diode dv/dt ruggedness	dv/dt	Turn-on slew rate, repetitive	200	V/ns
Power dissipation	P _{tot} **	T _C =25 °C	97	W
Operating junction & storage temperature	T _j , T _{storage}	Continuous	-55175	°C
Soldering temperature	T _{solder}	Wave soldering leads	260	°C
Mounting torque		M3 Screw	1	N-m

Notes:

^{*} EAS of 67 mJ is based on starting Tj = 25° C, L = 1.0 mH, IAS = 11.58 A, V = 50 V.

^{**} Typical Rth_{JC} used

Electrical Characteristics, at T_j=25 °C, unless otherwise specified

Characteristics	Symbol	Conditions	Values			l lmit
			min.	typ.	max.	Unit
DC blocking voltage	V _{DC}	T _j =25 °C	650	-	-	V
Diode forward voltage		I _F =10A, T _j =25 °C	-	1.50	1.60	V
	V_{F}	I _F =10A, T _j =125 °C	-	1.59	-	
		I _F =10A, T _j =175 °C	-	1.72	2.20	
Reverse current	I _R	V _R =650V, T _j =25 °C	-	2	25	μА
		V _R =650V, T _j =125 °C	-	11	-	
		V _R =650V, T _j =175 °C	-	36	250	
Total capacitive charge	Q _C	V _R =400V, T _j =25 °C	-	26	-	nC
Total capacitance		V _R =1V, f=1 MHz	-	419	-	pF
	С	V _R =200V, f=1 MHz	-	51	-	
		V _R =400V, f=1 MHz	-	43	-	

Thermal Characteristics

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	Ollit
Thermal resistance, junction-case	R _{thJC}	-	-	1.54	2.1	°C/W

Typical Performance

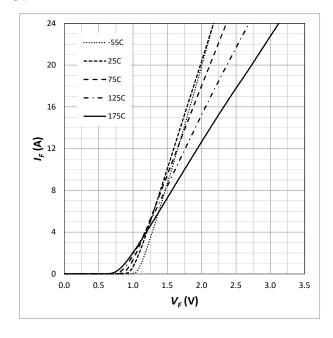


Fig. 1 Forward Characteristics (parameterized on T_i)

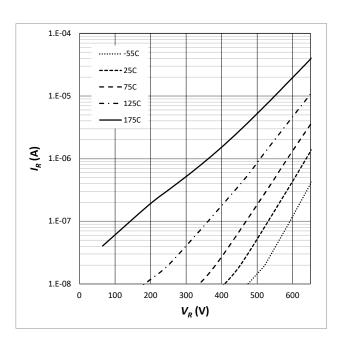
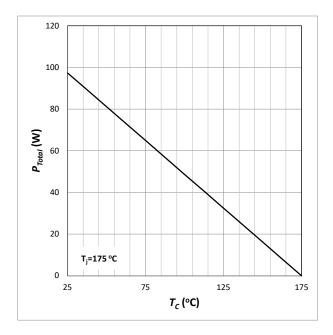


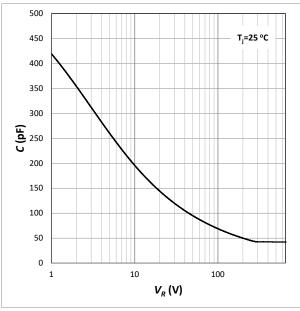
Fig. 2 Reverse Characteristics (parameterized on T_i)



140 Duty cycle **-**100% 120 - 50% 100 10% 80 /_F(A) 60 40 20 T_i=175 °C 0 105 25 45 65 125 145 165 T_c (°C)

Fig. 3 Power Derating

Fig. 4 Current Derating





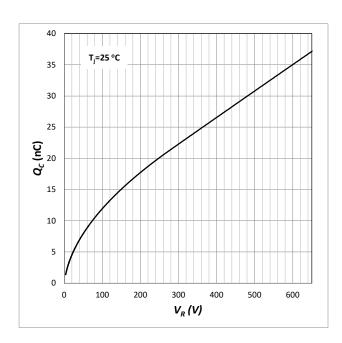
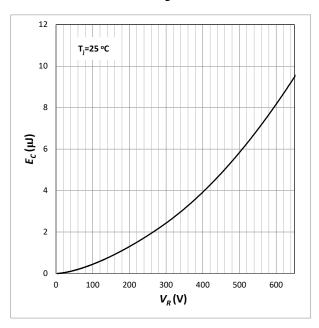


Fig. 6 Capacitive Charge



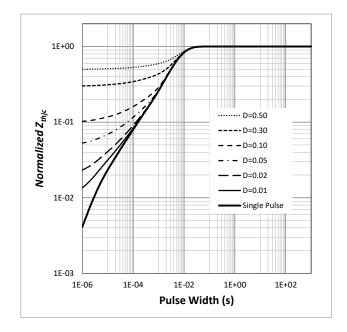
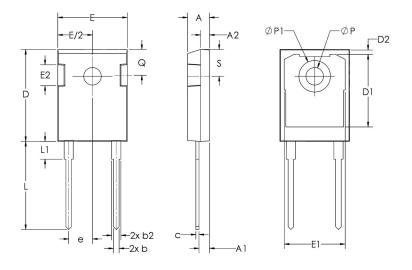


Fig. 7 Typical Capacitance Stored Energy

Fig. 8 Transient Thermal Impedance

Package Dimensions TO-247-2L



Sym	Millin	neters	Inches		
Sym	Min	Max	Min	Max	
Α	4.70	5.31	0.185	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b2	1.65	2.39	0.065	0.094	
С	0.38	0.89	0.015	0.035	
D	20.80	21.46	0.819	0.845	
D1	13.08	17.65	0.515	0.695	
D2	0.51	1.35	0.020	0.053	
E	15.49	16.26	0.610	0.640	
E1	13.46	14.16	0.530	0.557	
E2	3.43	5.49	0.135	0.216	
е	5.44	BSC	.214 BSC		
L	19.81	20.32	0.780	0.800	
L1	4.10	4.50	0.161	0.177	
ØP	3.56	3.66	0.140	0.144	
ØP1	7.06	7.39	0.278	0.291	
Q	5.38	6.20	0.212	0.244	
S	6.04	6.30	0.238	0.248	
Х	10°		10°		
Υ	3°		3	0	

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Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.SemiQ.com.

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